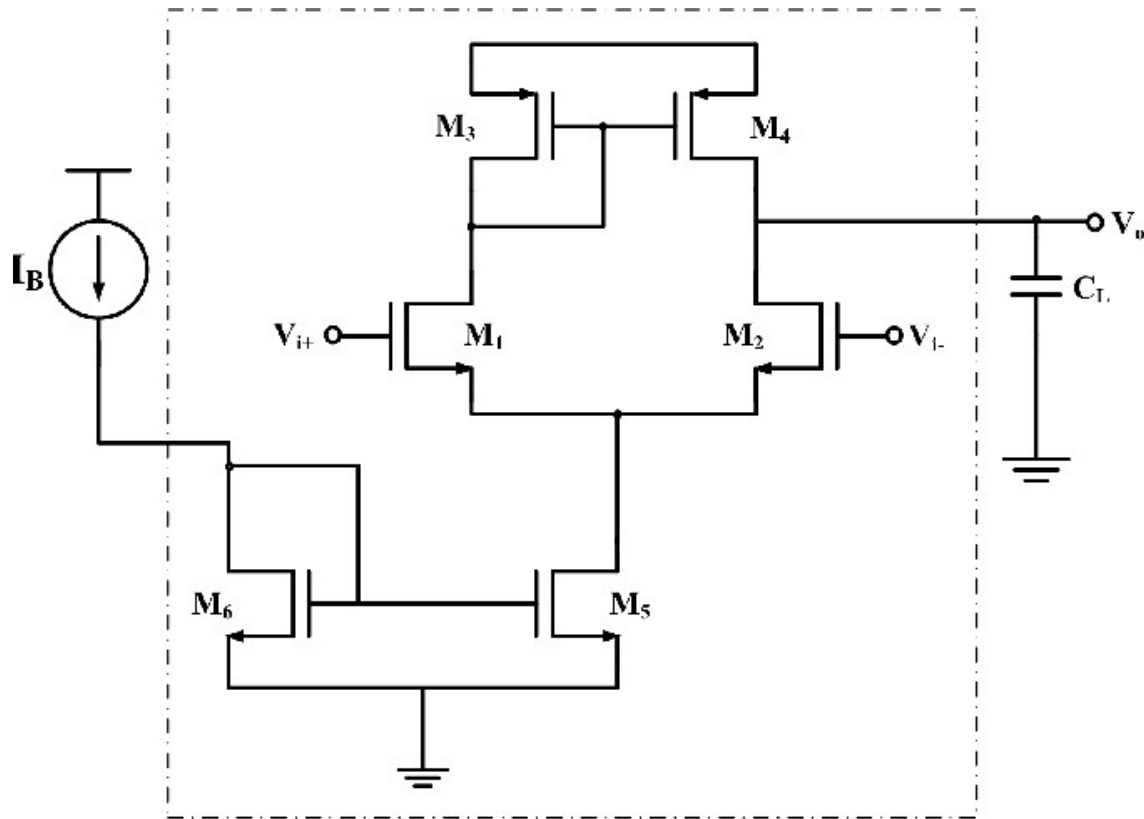


## Differential Amplifier



Question: Given: Obtain  $|A_v|=20\text{dB}$ , bandwidth =  $5\text{MHz}$ , and  $V_{DD} = 1.8\text{V}$ ,  $C_{LOAD}=10\text{pF}$ , ( $\mu_n C_{ox}$  = given or take it from previous chapter of nch\_25 mosfet), slew rate =  $5\text{ V}/\mu\text{sec}$ , Input common mode range =  $0.8\text{V}$  to  $1.6\text{V}$ , power dissipation =  $0.3\text{mW}$  .(betaeff =  $\mu_n C_{ox}(W/L)$ , and  $\mu_n C_{ox}$  of nch\_25= $276\mu\text{A}/\text{V}^2$  and  $\mu_p C_{ox}$  of pch\_25= $88\mu\text{A}/\text{V}^2$  and nmos to be used nch\_25 and pmos to be used pch\_25,  $V_{th}$  of nch\_25= $552\text{mV}$  and  $V_{th}$  of pch\_25= $500\text{mV}$ ,  $V_{OV}$  of nmos = $350\text{mV}$  and  $V_{OV}$  of pmos= $380\text{mV}$ )

Answer: follow the below steps:

1. Make sure the transistor is in saturation region for amplifier case.
2. Tail current  $I_0 = C_L * (\text{Slew rate}) = (10\text{pF}) * (5\text{ V}/\mu\text{sec}) = 50\mu\text{A} = I_B$
3. General equation of Input common mode range,
  - i) If  $V_{CM}$  decreases,  $M_5$  is carrying a current  $I_0$  and  $M_1$  and  $M_2$  is carrying current  $I_0/2$ . For carrying a current  $I_0/2$ , the transistor

must have fixed  $V_{GS}$ , therefore if  $V_{CM}$  decreases, (here  $V_{i+}=V_{i-}=V_{CM}$ ),

$V_X$  decreases and  $M_0$  will go to triode region.

$$(V_{i,CM})_{\min}=V_{GS1}+V_{DSAT}(\text{of } M_5)$$

If  $V_{CM}$  increases,  $M_1$  and  $M_2$  gets affected and will go to triode region,

$$(V_{i,CM})_{\max}=V_{DD} - V_{SG}(\text{of } M_3) + V_{th}(\text{of } M_1)$$

**Note: The same logic of calculating input biasing range holds good for any circuit.**

4. Output common mode range;

If  $V_{out}$  decreases,  $M_2$  gets in triode region, and to keep it in saturation region  $(V_{out})_{\min} = V_{OV}(\text{of } M_5) + (V_{OV}(\text{of } M_2))$

If  $V_{out}$  increases,  $M_4$  gets in triode region, and to keep it in saturation region  $(V_{out})_{\max} = V_{DD} - V_{OV}(\text{of } M_4)$

5. Calculate  $g_m$ ,

$$g_m = \text{Bandwidth} * 2 * \pi * C_L,$$

$$g_m = 314.16 \mu A/V^2$$

6. Calculation of W/L ratio of all the Mosfets:

For  $M_3$  and  $M_4$ : (calculate it from drain current equation in saturation region)

$$I_D = 1/2(\mu_p C_{ox}(W/L)(V_{SG} - |V_{th}|)^2$$

Note:  $I_0 = 50\mu A$  (flowing in tail mosfet  $M_5$ ), the currents flowing in  $M_1$  and  $M_3 = I_0/2 = 25\mu A$  and the currents flowing in  $M_2$  and  $M_4 = I_0/2 = 25\mu A$ . Basically, tail current flowing is divide by 2 in differential amplifier as it almost symmetrical circuit.

$$I_3 = I_4 = I_0/2 = 25\mu A = (1/2)(\mu_n C_{ox}(W/L)(V_{GS} - V_{th})^2$$

$$50\mu = 87.2013\mu(W/L)_{3,4}(0.38)^2$$

$$(W/L)_{3,4} = 3.97$$

$$(W/L)_{3,4} = 4$$

For M<sub>1</sub> and M<sub>2</sub>: (calculate it from g<sub>m</sub>)

M<sub>1</sub>, M<sub>2</sub> current flowing is 25μA ie I<sub>0</sub>/2

$$\frac{\partial I}{\partial v_{GS}} = g_m = \mu_n C_{ox} (W/L)_{1,2} (V_{GS} - V_{th})$$

$$(W/L)_{1,2} = g_m^2 / (2I_D \mu_n C_{ox}) \dots \text{here } I_D = I_0/2$$

$$(W/L)_{1,2} = 7$$

For M<sub>5,6</sub>: (calculate by drain current equation in saturation region and take V<sub>overdrive</sub> = V<sub>DSAT</sub> = V<sub>GS</sub> - V<sub>th</sub> = V<sub>OV</sub>)

For M<sub>5</sub> and M<sub>6</sub>, current flowing is 50μA ie I<sub>0</sub> and for M<sub>1</sub>, M<sub>2</sub>, M<sub>3</sub>, M<sub>4</sub> current flowing is 25μA ie I<sub>0</sub>/2

$$I_0 = I_D = 1/2 (\mu_n C_{ox} (W/L) (V_{GS} - V_{th})^2$$

$$50\mu = (1/2) (275.78\mu) (W/L)_{5,6} (0.3)^2$$

$$(W/L)_{5,6} = 4$$

7. For these calculated values, we will not get the desired specification and after above all the steps, we next improvise accordingly.